NSN 5962-01-203-3165



Memory Microcircuit - Page 1 of 2 View Online at https://aerobasegroup.com/nsn/5962-01-203-3165 **Body Length:** 1.290 inches **Body Width:** Between 0.500 inches and 0.610 inches **Body Height:** 0.165 inches **Maximum Power Dissipation Rating:** 950.0 milliwatts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Programmed and bipolar and monolithic **Inclosure Material:** Ceramic and glass **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Transistor-transistor logic **Input Circuit Pattern:** 14 input **Case Outline Source And Designator:** D-3 mil-m-38510 **Terminal Surface Treatment:** Solder or solder **Memory Device Type:** Rom **Precious Material And Location:** Terminal surfaces option gold **Precious Material:** Gold **Test Data Document:** 89954-144a9552 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 24 printed circuit Shelf Life: N/a **Unit Of Measure:**

Demilitarization: Yes - demil/mli

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